



INTEGRATED CIRCUIT

東芝

TECHNICAL DATA

ZERO VOLTAGE SWITCH

- Temperature Control for Heaters and so Forth
- AC Line Operation at 50Hz or 60Hz
- High Peak Output Current (Pulse)...90mA Min.
- Built-in Protection Circuit for Opened or Shorted Sensor

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
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MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$)

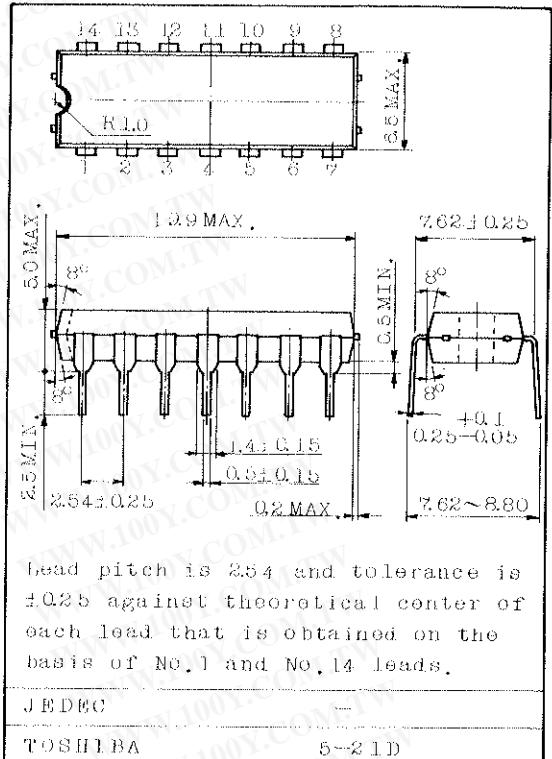
CHARACTERISTIC	SYMBOL	RATING	UNIT
DC Supply Voltage (2-7Pin)	V _{CC}	14	V
DC Supply Voltage (2-8Pin)	V _{CC}	14	V
Peak Supply Current (5-7Pin)	I _{CC} (peak)	±50	mA
Peak Supply Current (12-7Pin)	I _{CC} (peak)	±50	mA
Input Voltage (9Pin, 13Pin)	V ₉ , V ₁₃	V _S	V
Differential Input Voltage (9-13Pin)	V _{IN}	14	V
Protection Input Voltage (14Pin)	V ₁₄	V _S	V
Protection Input Current (1Pin)	I ₁	10	mA
Power Dissipation	P _D	625	mW
Operating Temperature	T _{opr}	-30 ~ 75	°C
Storage Temperature	T _{stg}	-55 ~ 150	°C

TA7606P

TOSHTBA BIPOLAR LINEAR INTEGRATED CIRCUIT

SILICON MONOLITHIC

Unit in mm





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TOSHIBA

TECHNICAL DATA

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ELECTRICAL CHARACTERISTICS

(Ta=25°C, AC Line Voltage=100Vrms, 50-60Hz)

CHARACTERISTIC		SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
DC Supply Voltage	Inhibit Mode	V _{CC}	1	R _S =6.8kΩ	5.8	6.3	6.8	V
	Pulse Mode				5.5	6.1	-	V
Gate Trigger Current		I _{GT(4)}	2	Term. 3 and 2 Connected V _{GT} =1V	-	105	-	mA
Peak Output Current (Pulsed)	Internal Power Supply	I _{OP(4)}	2	Term. 3 Open V _{GT} =0V	50	85	-	mA
				Term. 3 and 2 Connected V _{GT} =0V	90	130	-	mA
	External Power Supply	I _{OP(4)}	3	Term. 3 Open V _{GT} =0V, V _S =12V	130	170	-	mA
				Term. 3 and 2 Connected V _{GT} =0V V _{CC} =12V	190	250	-	mA
Total Gate Pulse Duration	Positive dv/dt	t _P	4	R _S =6.8kΩ, C _(EXT.) =0	110	135	165	ns
	Negative dv/dt	t _N			110	135	165	μs
Gate Pulse Duration (After Zero Crossing)	Positive dv/dt	t _{P1}			-	50	-	μs
	Negative dv/dt	t _{N1}			-	85	-	μs
Output Leakage Current		I ₄	-	-	-	-	5	μA
Input Bias Current		I _B	5	V _{CC} =6V	-	-	5.6	μA
Protection Threshold Voltage	High Level	V _{THH}	6	V _{CC} =6V	4.80	5.05	5.30	V
	Low Level	V _{THL}			0.75	1.10	1.34	V

* Gate pulse duration in 60Hz applications is approximately 15% shorter than shown in the above.



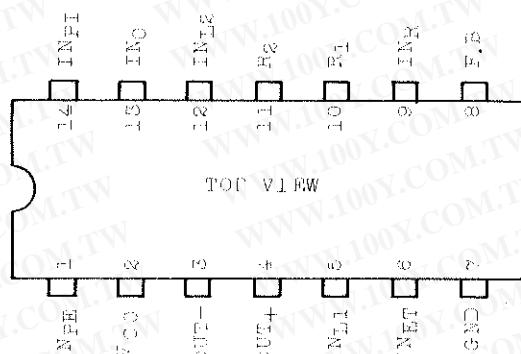
INTEGRATED CIRCUIT

TA7606P

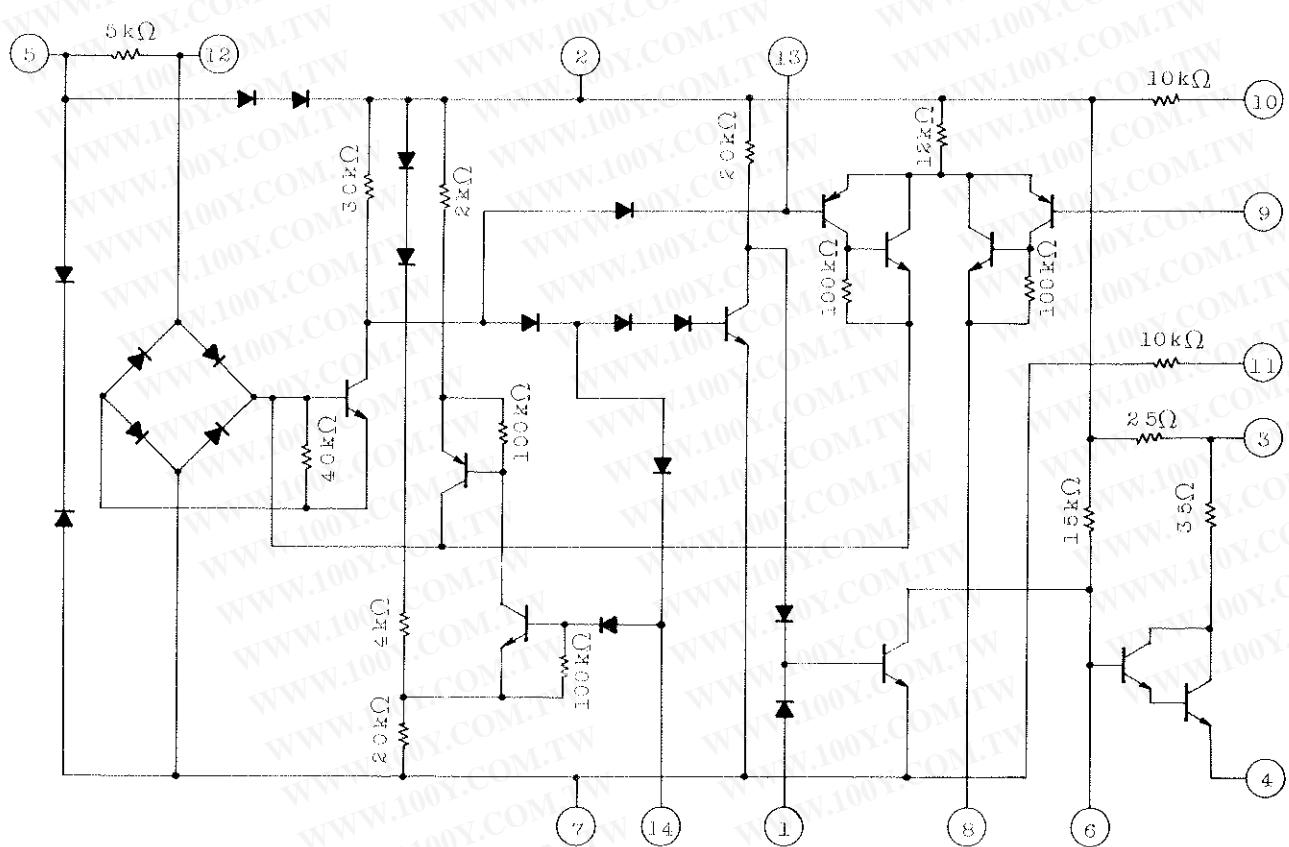
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TECHNICAL DATA

PIN CONNECTION



EQUIVALENT CIRCUIT



1. INP1 : EXTERNAL PROTECTION INPUT
2. VCC : DC SUPPLY
3. OUT- : -TRIGGER PULSE OUTPUT
4. OUT+ : +TRIGGER PULSE OUTPUT
5. INL1 : AC LINE INPUT
6. INET : EXTERNAL TRIGGER INPUT
7. GND : GROUND
8. F.B. : FEEDBACK
9. INR : REFERENCE INPUT
10. R1 : REFERENCE RESISTER
11. R2 : REFERENCE RESISTER
12. INL2 : AC LINE INPUT
13. INC : CONTROL SIGNAL INPUT
14. INP1 : INTERNAL PROTECTION INPUT



INTEGRATED CIRCUIT

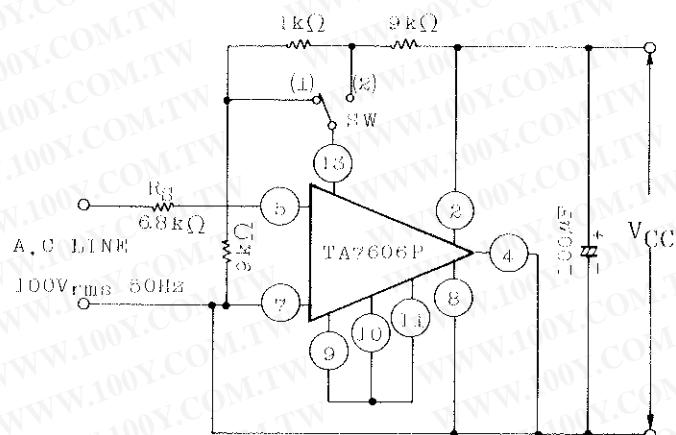
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TECHNICAL DATA

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TEST CIRCUIT

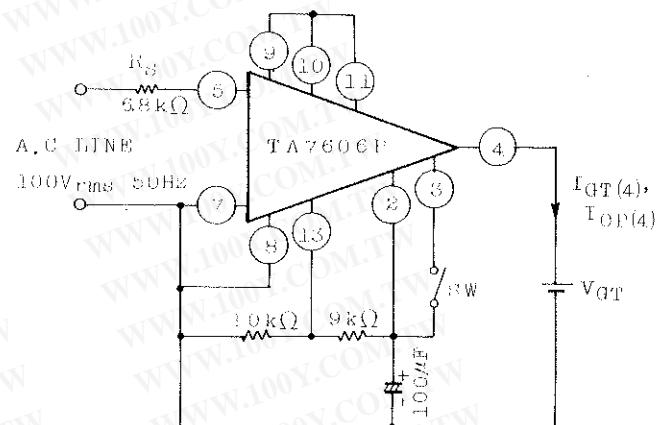
1. V_{CC}



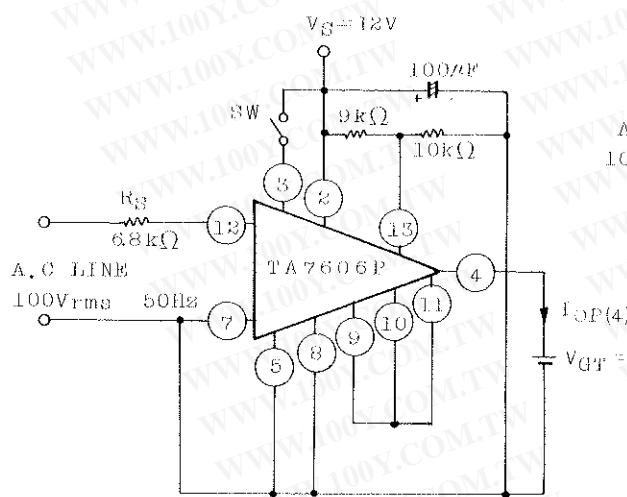
SW → (1) : INHIBIT MODE

SW → (2) : PULSE MODE

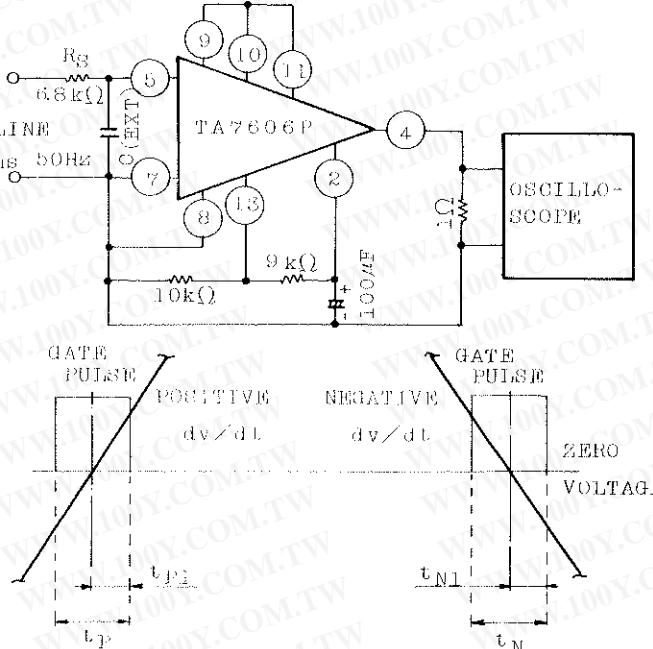
2. I_{GT(4)}, I_{OP(4)}, INTERNAL POWER SUPPLY

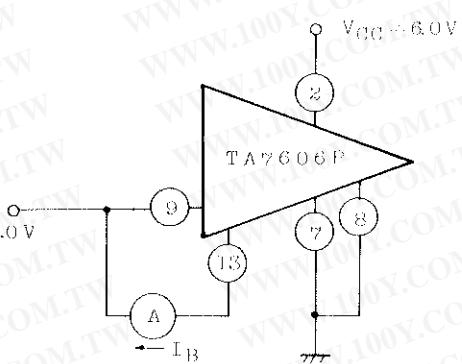
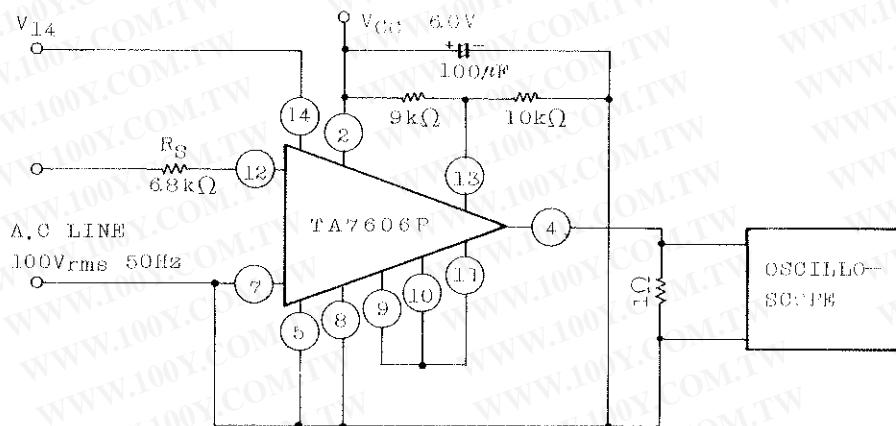


3. I_{OP(4)} EXTERNAL POWER SUPPLY



4. t_P, t_N, t_{P1}, t_{N1}



5. I_B 6. V_{TH^H} , V_{TH^L}  V_{TH^H} : The high level of V_{14} at the output off. V_{TH^L} : The low level of V_{14} at the output off.

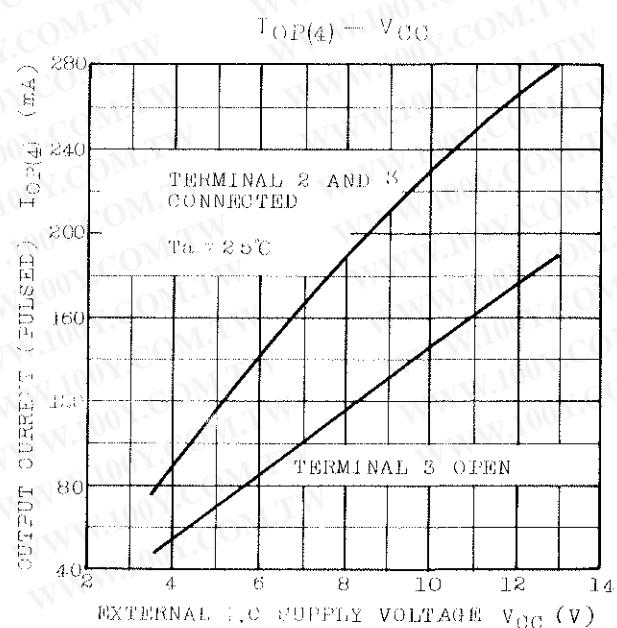
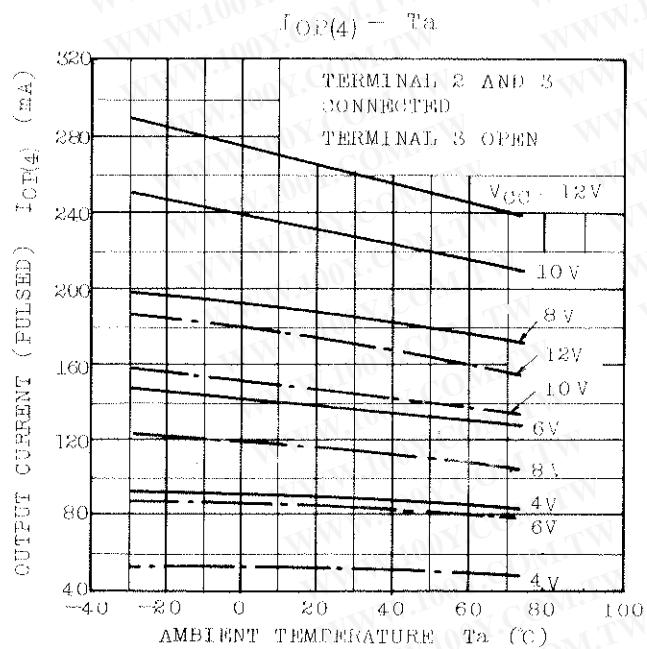
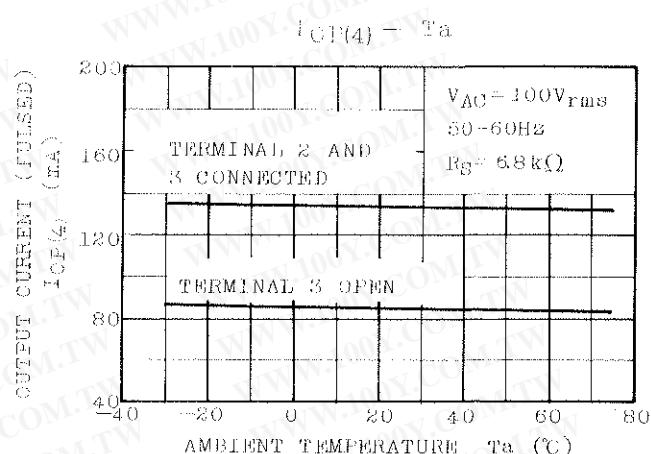
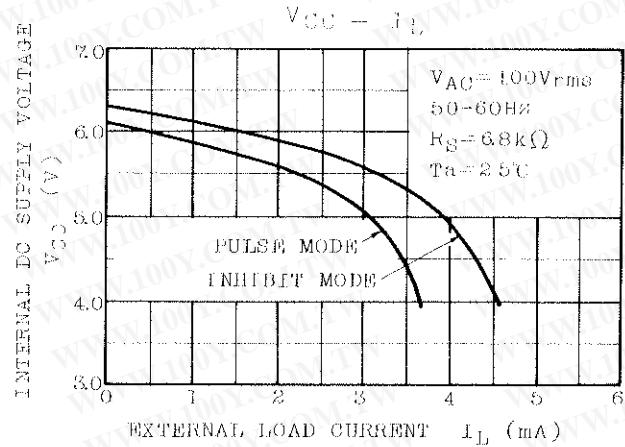
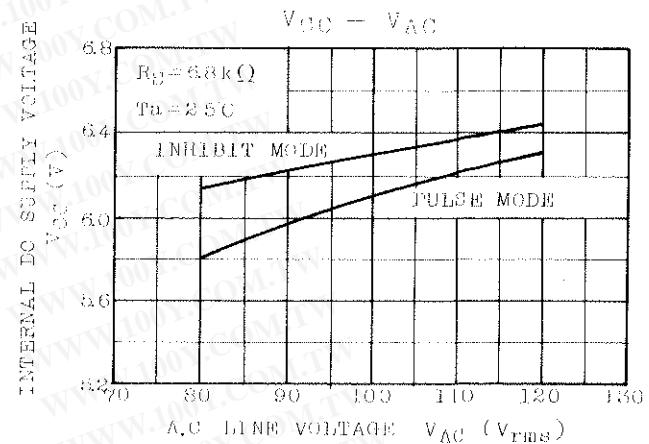
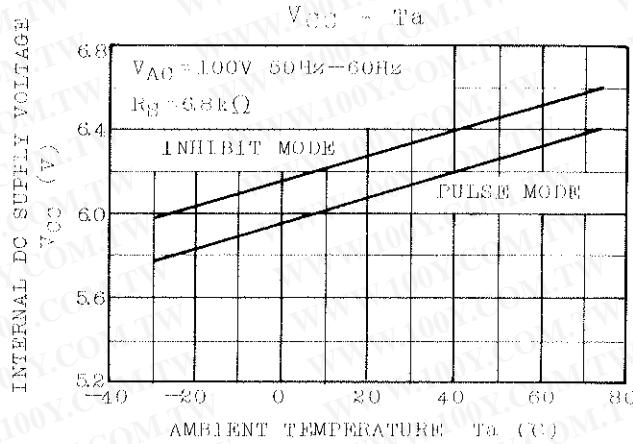


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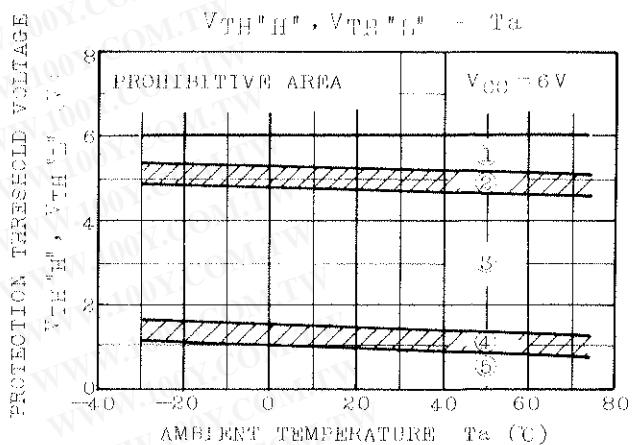
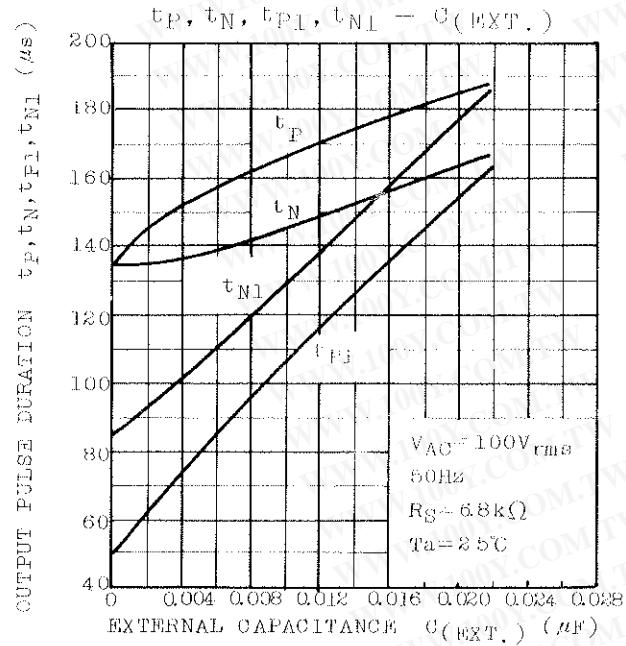
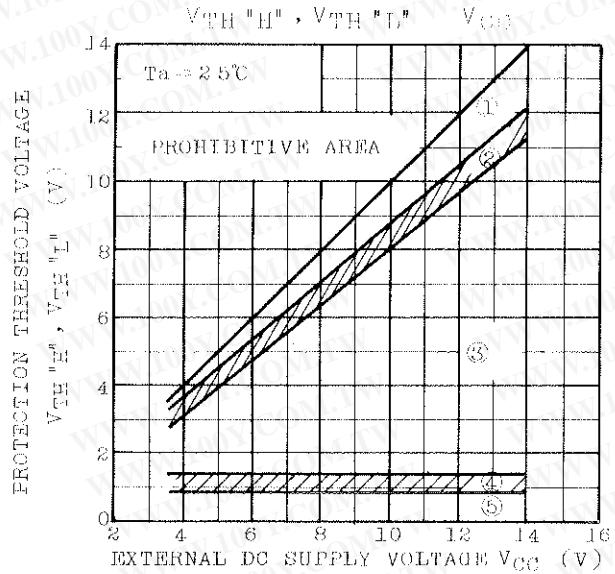
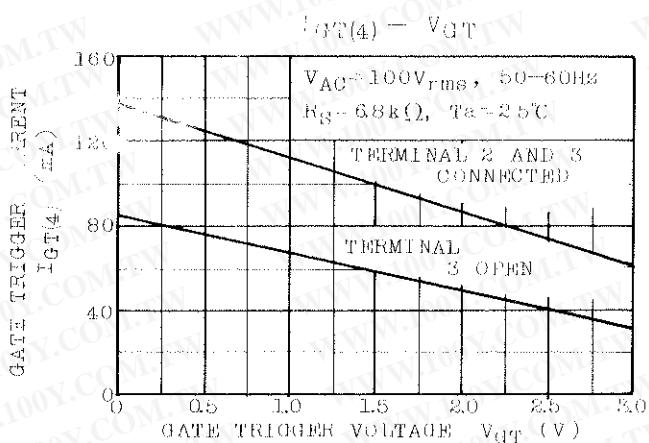


INTEGRATED CIRCUIT

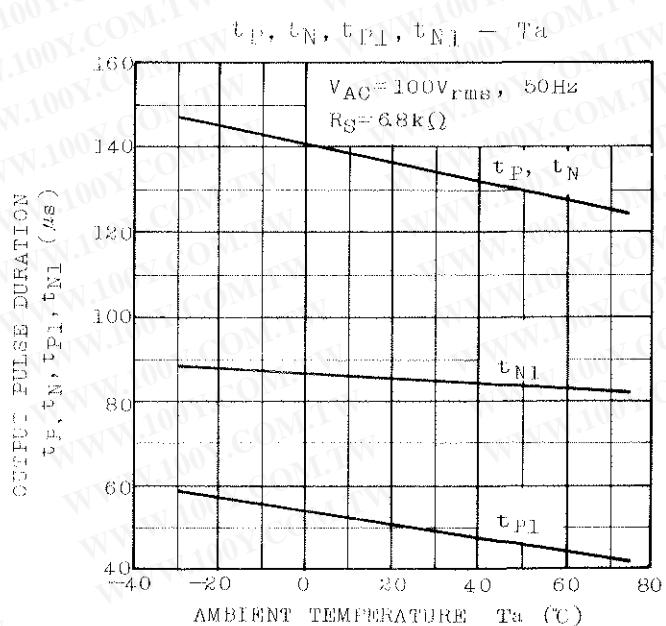
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TECHNICAL DATA

TA7606P



- ① AREA OF OUTPUT OFF
- ② AREA OF UNCERTAIN OPERATION
- ③ AREA OF NORMAL OPERATION
- ④ AREA OF UNCERTAIN OPERATION
- ⑤ AREA OF OUTPUT OFF





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TECHNICAL DATA

TA7606P

APPLICATION

1. ON-OFF CONTROLLER (HEATER)

a. I^+ , III^+ MODE TRIGGER

(STANDARD APPLICATION)

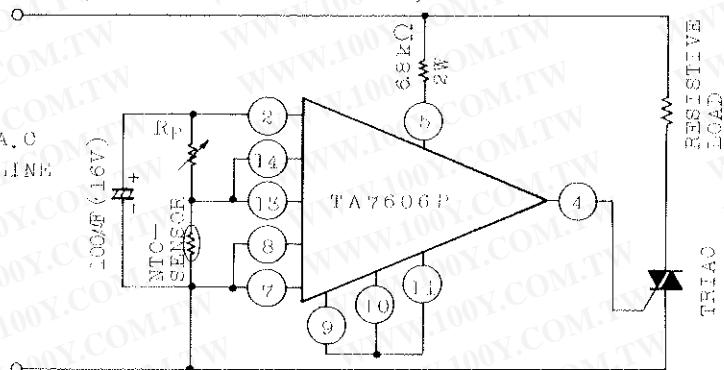


Fig. 1-a

- . Mind the gate sensitivity (I^+ and III^+ modes) of a triac, because the TA7606P supplied positive gate pulses.
- . The triac is turned off by the built-in protection circuit if the sensor opened or shorted.
- . Open the terminal 14 if a built-in protection circuit is not necessary.
- . Connect the terminal 2 and 3 if the output current is too low.
- . Set the value of R_p and sensor resistance between $5k\Omega$ and $50k\Omega$.
- . If the output pulse duration is too short, it gives the longer effective gate pulse duration to connect a external capacitor between the terminal 5 and 7.

b. I^- , III^- MODE TRIGGER (HEATER)

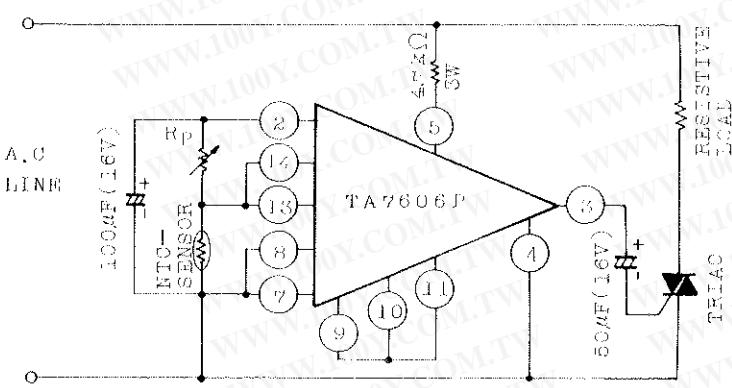


Fig. 1-b(a)

- . This circuit is used if I^+ and III^+ mode trigger is impossible.
(Generally III^+ mode gate sensitivity is worst.)
- . The curve in Fig. 1-b(b) shows the approximate gate current as a function of gate voltage.

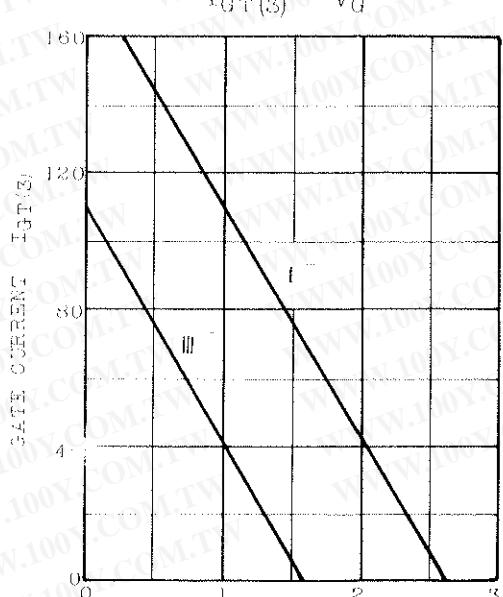


Fig. 1-b(b)



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TECHNICAL DATA

TA7606P

2. ON-OFF CONTROLLER WITH HYSTERESIS (HEATER)

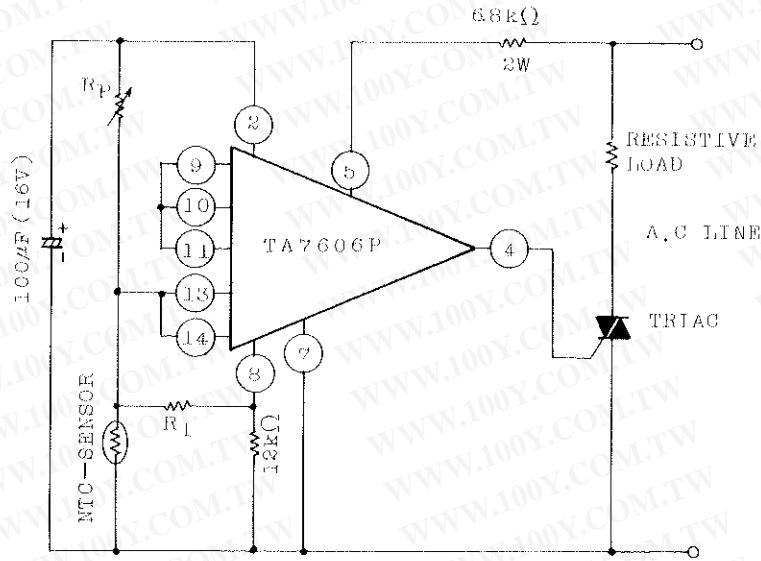


Fig.2 (a)

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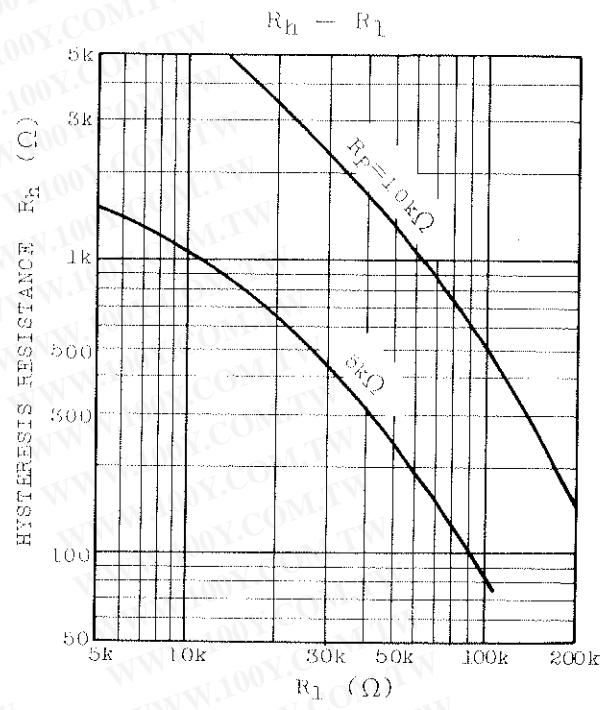


Fig.2 (b)

- The value of R_1 can change hysteresis shown in Fig.2 (b).
- The resistance between terminal 8 and GND can also change hysteresis.
- See application 1-a about a sensor and so forth.

3. ON-OFF CONTROLLER (EXTERNAL D.C. SUPPLY)

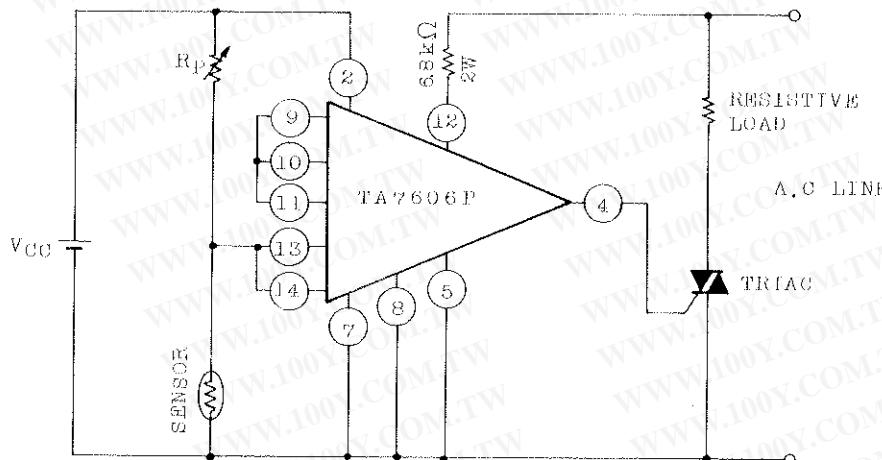


Fig.3

- See application 1-a about a sensor and so forth.